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# FDB024N06

## N-Channel PowerTrench® MOSFET

### 60 V, 265 A, 2.4 mΩ

#### Features

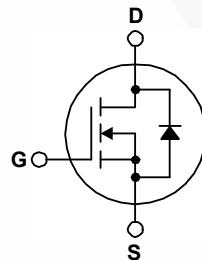
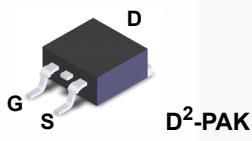
- $R_{DS(on)} = 1.8 \text{ mΩ}$  (Typ.) @  $V_{GS} = 10 \text{ V}$ ,  $I_D = 75 \text{ A}$
- Fast Switching Speed
- Low Gate Charge
- High Performance Trench Technology for Extremely Low  $R_{DS(on)}$
- High Power and Current Handling Capability
- RoHS Compliant

#### Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench® process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

#### Applications

- Synchronous Rectification for ATX / Server / Telecom PSU
- Battery Protection Circuit
- Motor Drives and Uninterruptible Power Supplies
- Renewable System



**MOSFET Maximum Ratings**  $T_C = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter		FDB024N06	Unit
$V_{DSS}$	Drain to Source Voltage		60	V
$V_{GSS}$	Gate to Source Voltage		$\pm 20$	V
$I_D$	Drain Current	- Continuous ( $T_C = 25^\circ\text{C}$ , Silicon Limited)	265	A
		- Continuous ( $T_C = 100^\circ\text{C}$ , Silicon Limited)	190	
		- Continuous ( $T_C = 25^\circ\text{C}$ , Package Limited)	120	
$I_{DM}$	Drain Current	- Pulsed (Note 1)	1060	A
$E_{AS}$	Single Pulsed Avalanche Energy (Note 2)		2531	mJ
$dv/dt$	Peak Diode Recovery $dv/dt$ (Note 3)		6.0	V/ns
$P_D$	Power Dissipation ( $T_C = 25^\circ\text{C}$ )	395	W	$^\circ\text{C}/\text{W}$
		- Derate Above $25^\circ\text{C}$	2.6	
$T_J, T_{STG}$	Operating and Storage Temperature Range		-55 to +175	$^\circ\text{C}$
$T_L$	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	$^\circ\text{C}$

#### Thermal Characteristics

Symbol	Parameter	FDB024N06	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.38	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	62.5	
	Thermal Resistance, Junction to Ambient (1 in <sup>2</sup> Pad of 2-oz Copper), Max.	40	

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDB024N06	FDB024N06	D <sup>2</sup> -PAK	Tape and Reel	330 mm	24 mm	800 units

## Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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### Off Characteristics

$\text{BV}_{\text{DSS}}$	Drain to Source Breakdown Voltage	$I_D = 250 \mu\text{A}, V_{GS} = 0 \text{ V}$	60	-	-	V
$\Delta \text{BV}_{\text{DSS}} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}, \text{Referenced to } 25^\circ\text{C}$	-	0.04	-	$\text{V}^\circ\text{C}$
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	1	$\mu\text{A}$
		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_C = 150^\circ\text{C}$	-	-	500	
$I_{\text{GSS}}$	Gate to Body Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	$\pm 100$	nA

### On Characteristics

$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$	2.5	3.5	4.5	V
$R_{DS(\text{on})}$	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 75 \text{ A}$	-	1.8	2.4	$\text{m}\Omega$
$g_{\text{FS}}$	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_D = 75 \text{ A}$	-	200	-	S

### Dynamic Characteristics

$C_{\text{iss}}$	Input Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	11190	14885	pF
$C_{\text{oss}}$	Output Capacitance		-	1610	2140	pF
$C_{\text{rss}}$	Reverse Transfer Capacitance		-	750	1125	pF
$Q_{\text{g}(\text{tot})}$	Total Gate Charge at 10V	$V_{DS} = 48 \text{ V}, I_D = 75 \text{ A}, V_{GS} = 10 \text{ V}$	-	174	226	nC
$Q_{\text{gs}}$	Gate to Source Gate Charge		-	54	-	nC
$Q_{\text{gd}}$	Gate to Drain "Miller" Charge		(Note 4)	-	50	-

### Switching Characteristics

$t_{\text{d}(\text{on})}$	Turn-On Delay Time	$V_{DD} = 30 \text{ V}, I_D = 75 \text{ A}, V_{GS} = 10 \text{ V}, R_G = 25 \Omega$	-	134	278	ns
$t_r$	Turn-On Rise Time		-	324	658	ns
$t_{\text{d}(\text{off})}$	Turn-Off Delay Time		-	348	706	ns
$t_f$	Turn-Off Fall Time		(Note 4)	-	250	510

### Drain-Source Diode Characteristics

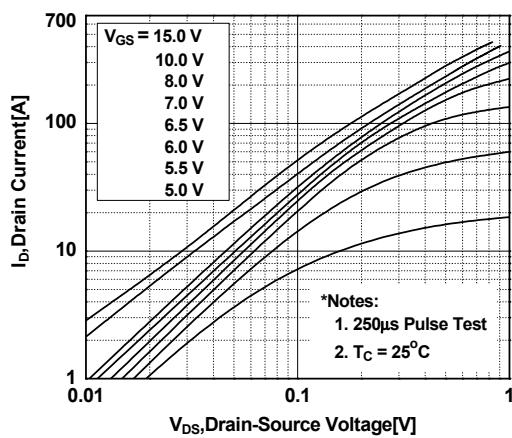
$I_S$	Maximum Continuous Drain to Source Diode Forward Current	-	-	265	A	
$I_{\text{SM}}$	Maximum Pulsed Drain to Source Diode Forward Current	-	-	1060	A	
$V_{SD}$	Drain to Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{SD} = 75 \text{ A}$	-	-	$1.3 \text{ V}$	
$t_{\text{rr}}$	Reverse Recovery Time	$V_{GS} = 0 \text{ V}, I_{SD} = 75 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	69	-	ns
$Q_{\text{rr}}$	Reverse Recovery Charge		-	152	-	nC

#### Notes:

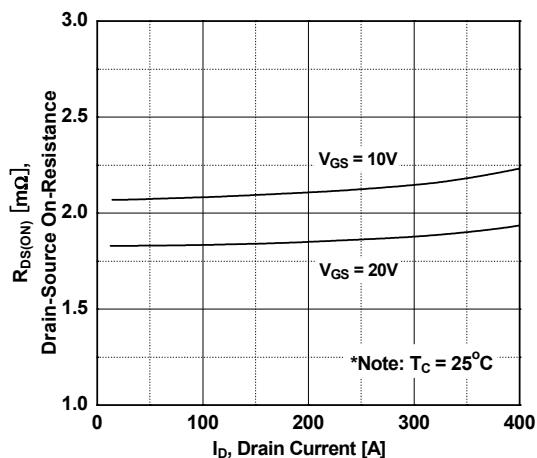
1. Repetitive rating: pulse-width limited by maximum junction temperature.
2. L = 0.9 mH,  $I_{AS} = 75 \text{ A}, V_{DD} = 50 \text{ V}, R_G = 25 \Omega$ , starting  $T_J = 25^\circ\text{C}$ .
3.  $I_{SD} \leq 75 \text{ A}, dI/dt \leq 200 \text{ A}/\mu\text{s}, V_{DD} \leq \text{BV}_{\text{DSS}}$ , starting  $T_J = 25^\circ\text{C}$ .
4. Essentially independent of operating temperature typical characteristics.

## Typical Performance Characteristics

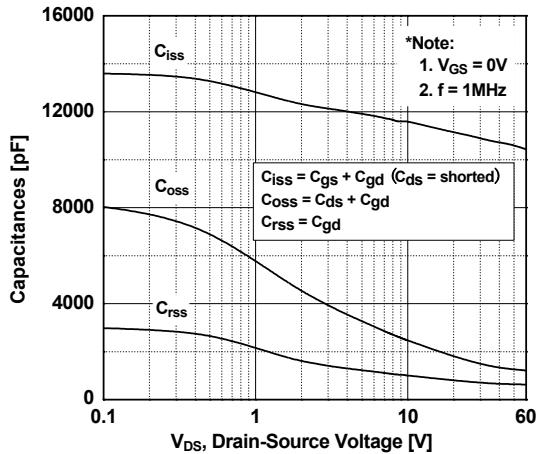
**Figure 1. On-Region Characteristics**



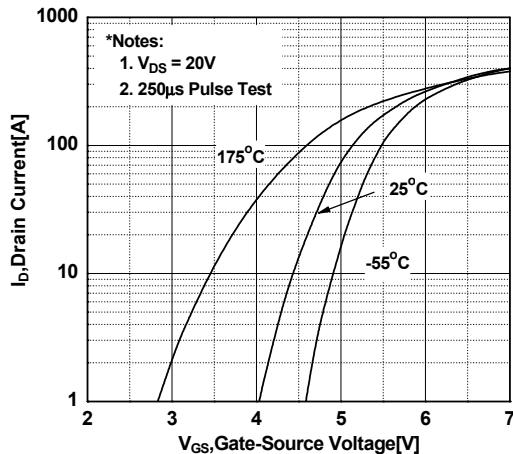
**Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage**



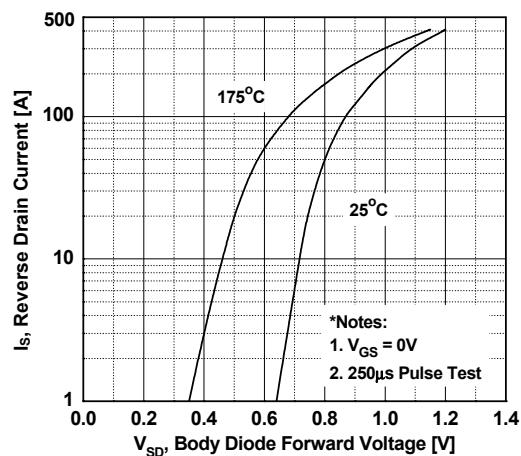
**Figure 5. Capacitance Characteristics**



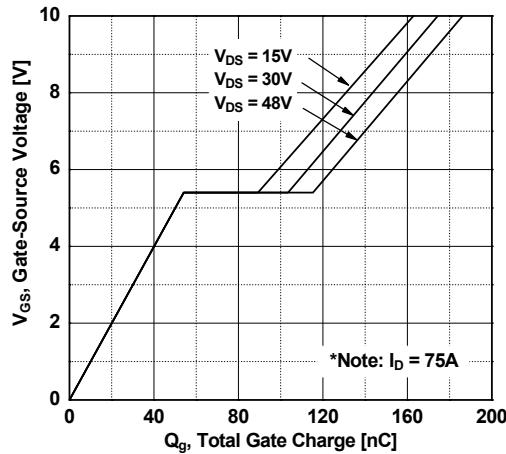
**Figure 2. Transfer Characteristics**



**Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature**

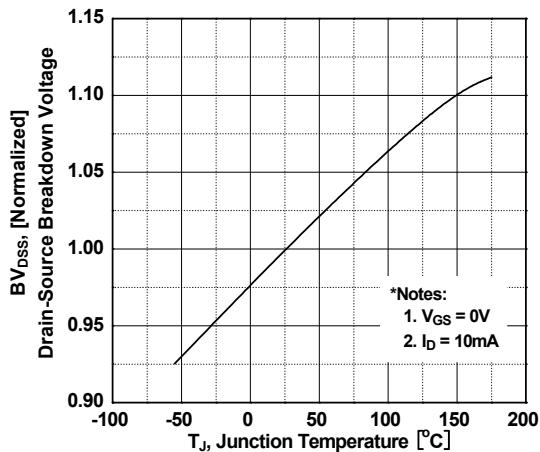


**Figure 6. Gate Charge Characteristics**

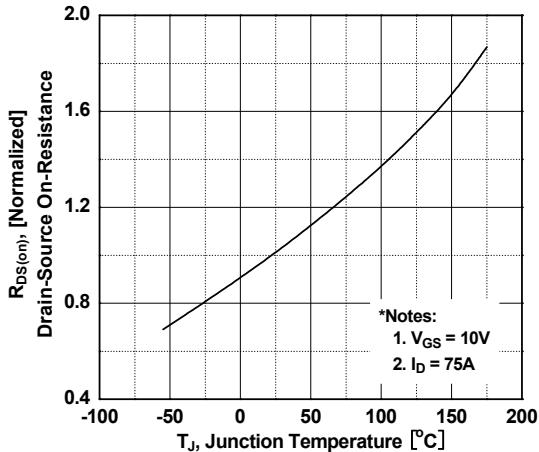


## Typical Performance Characteristics (Continued)

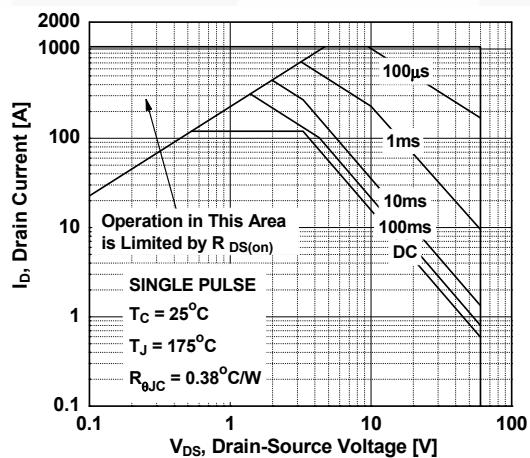
**Figure 7. Breakdown Voltage Variation vs. Temperature**



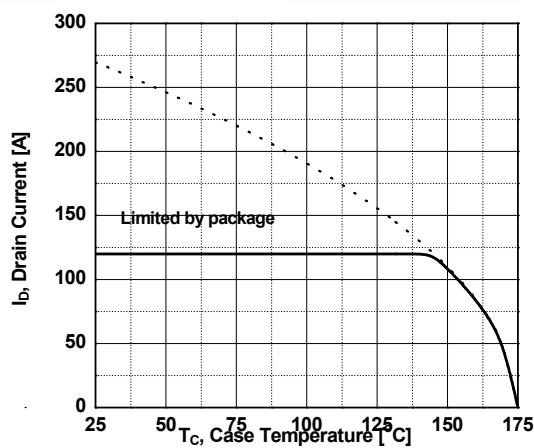
**Figure 8. On-Resistance Variation vs. Temperature**



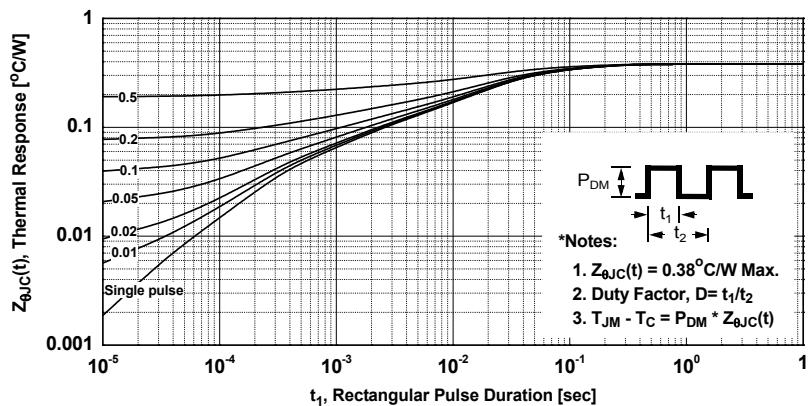
**Figure 9. Maximum Safe Operating Area**



**Figure 10. Maximum Drain Current vs. Case Temperature**



**Figure 11. Transient Thermal Response Curve**



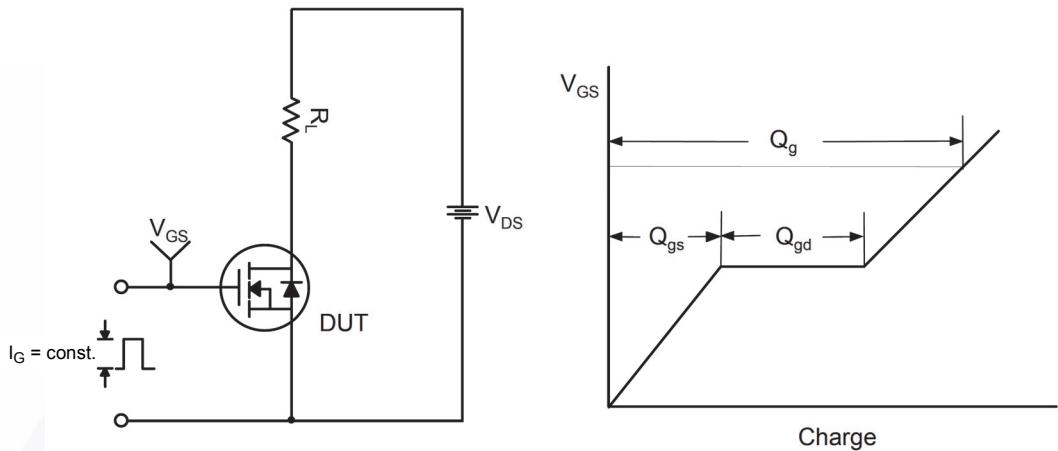


Figure 12. Gate Charge Test Circuit & Waveform

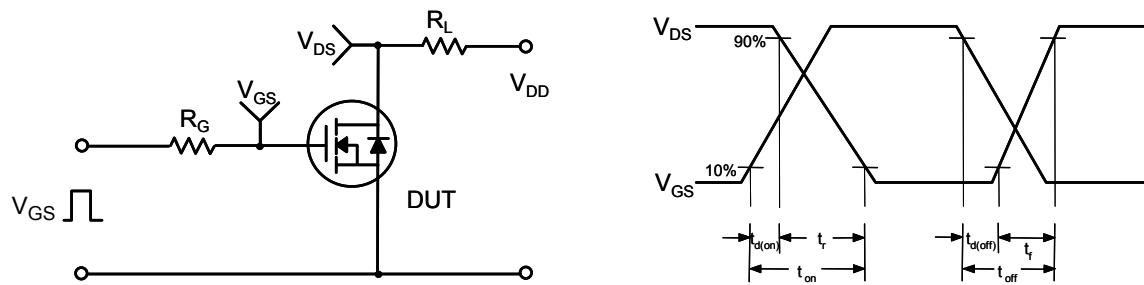


Figure 13. Resistive Switching Test Circuit & Waveforms

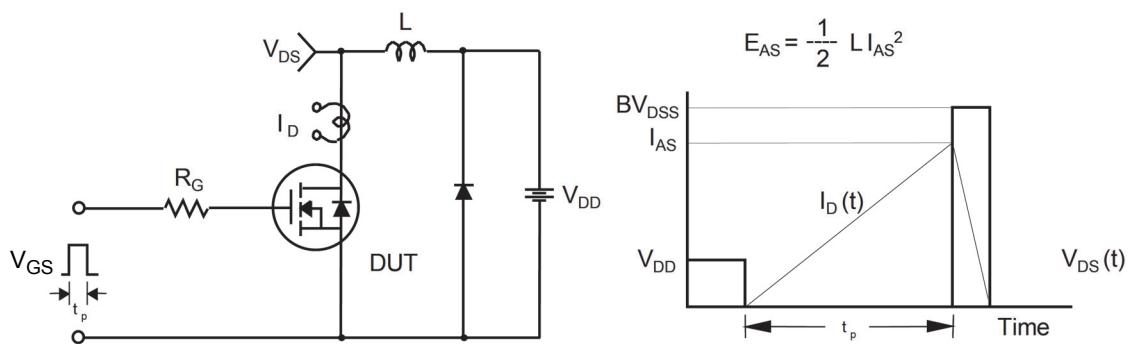


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

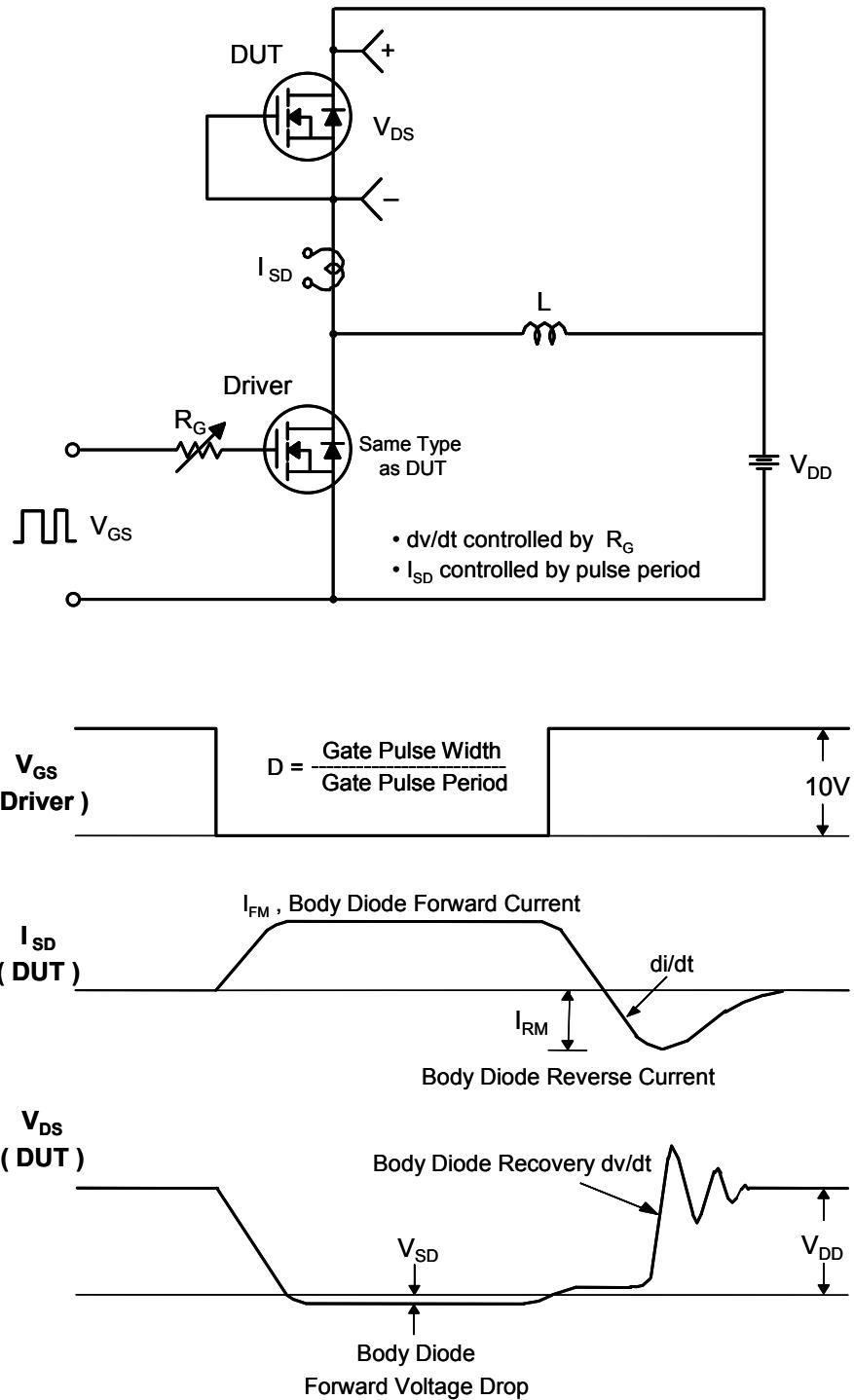
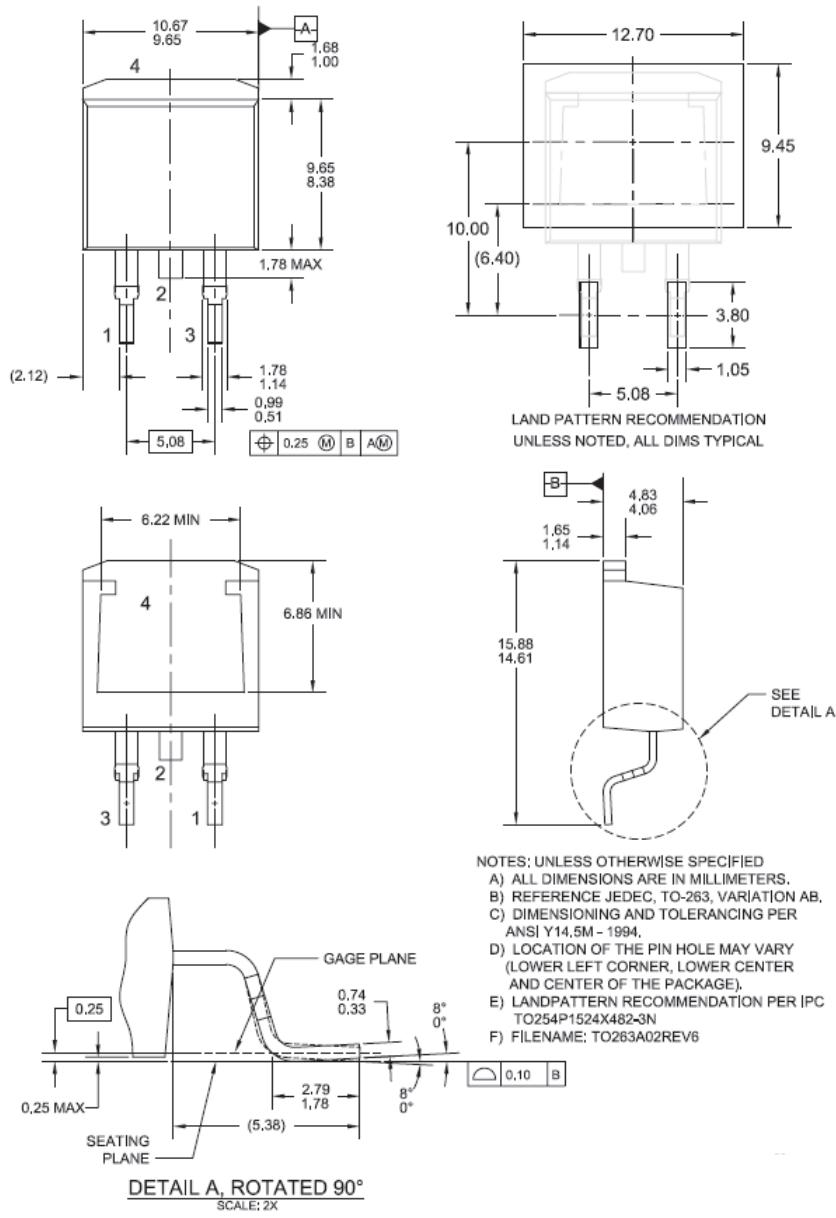


Figure 15. Peak Diode Recovery  $dv/dt$  Test Circuit & Waveforms

## Mechanical Dimensions



**Figure 16. TO263 (D<sup>2</sup>PAK), Molded, 2-Lead, Surface Mount**

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